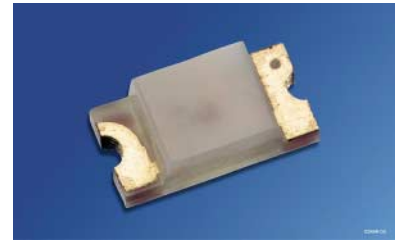


CHIPLED

LH N974



Besondere Merkmale

- **Gehäusotyp:** 1206
- **Besonderheit des Bauteils:** extrem kleine Bauform 3,2 mm x 1,6 mm x 1,1 mm
- **Wellenlänge:** 645 nm
- **Abstrahlwinkel:** extrem breite Abstrahlcharakteristik (160°)
- **Technologie:** GaAlAs
- **optischer Wirkungsgrad:** 3 lm/W
- **Verarbeitungsmethode:** für alle SMT-Bestücktechniken geeignet
- **Lötmethode:** IR Reflow Löten
- **Vorbehandlung:** nach JEDEC Level 2
- **Gurtung:** 8 mm Gurt mit 3000/Rolle, ø180 mm

Anwendungen

- optischer Indikator
- Flache Hinterleuchtung (LCD, Handy, Schalter, Display)
- Markierungsbeleuchtung (z.B. Stufen, Fluchtwege, u.ä.)
- Spielsachen

Features

- **package:** 1206
- **feature of the device:** extremely small package 3.2 mm x 1.6 mm x 1.1 mm
- **wavelength:** 645 nm
- **viewing angle:** extremely wide (160°)
- **technology:** GaAlAs
- **optical efficiency:** 3 lm/W
- **assembly methods:** suitable for all SMT assembly methods
- **soldering methods:** IR reflow soldering
- **preconditioning:** acc. to JEDEC Level 2
- **taping:** 8 mm tape with 3000/reel, ø180 mm

Applications

- optical indicators
- flat backlighting (LCD, cellular phones, switches, displays)
- marker lights (e.g. steps, exit ways, etc.)
- toys

Typ	Emissionsfarbe	Farbe der Lichtaustrittsfläche	Lichtstärke		Bestellnummer
Type	Color of Emission	Color of the Light Emitting Area	Luminous Intensity $I_F = 20 \text{ mA}$ $I_V \text{ (mcd)}$		Ordering Code
			min.	typ.	
LH N974	hyper-red	colorless diffused	7.1	15	Q62702-P5192

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11 \%$ ermittelt.
Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11 \%$.

*Anm.: Die Standardlieferform von Serientypen beinhaltet alle Gruppen. Einzelne Gruppen sind nicht erhältlich.
In einer Verpackungseinheit / Gurt ist immer nur eine Gruppe enthalten.*

*Note: The standard shipping format for serial types includes all groups. Individual groups are not available.
No packing unit / tape ever contains more than one luminous intensity group.*

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebstemperatur Operating temperature range	T_{op}	– 30 ... + 85	°C
Lagertemperatur Storage temperature range	T_{stg}	– 40 ... + 85	°C
Sperrschichttemperatur Junction temperature	T_j	+ 95	°C
Durchlassstrom Forward current	I_F	30	mA
Stoßstrom Surge current $t_p = 10 \mu s, D = 0.1$	I_{FM}	0.1	A
Sperrspannung Reverse voltage	V_R	5	V
Leistungsaufnahme Power consumption	P_{tot}	80	mW
Wärmewiderstand Thermal resistance Sperrschicht/Umgebung Junction/ambient Sperrschicht/Lötpad Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 5 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 5 \text{ mm}^2$)	$R_{th JA}$ $R_{th JS}$	750 430	K/W K/W

Kennwerte ($T_A = 25\text{ °C}$)**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 20\text{ mA}$	λ_{peak}	660	nm
Dominantwellenlänge ¹⁾ (typ.) Dominant wavelength ¹⁾ $I_F = 20\text{ mA}$	λ_{dom}	645	nm
Spektrale Bandbreite (typ.) Spectral bandwidth $I_F = 20\text{ mA}$	$\Delta\lambda$	20	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	160	Grad deg.
Durchlassspannung ²⁾ (typ.) Forward voltage ²⁾ (max.) $I_F = 20\text{ mA}$	V_F V_F	1.8 2.6	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 5\text{ V}$	I_R I_R	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.18	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.06	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	- 1.7	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 20\text{ mA}$	η_{opt}	3	lm/W

¹⁾ Wellenlängengruppen werden mit einer Stromeinprägungsdauer von 25 ms und einer Genauigkeit von $\pm 1\text{ nm}$ ermittelt.
Wavelength groups are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1\text{ nm}$.

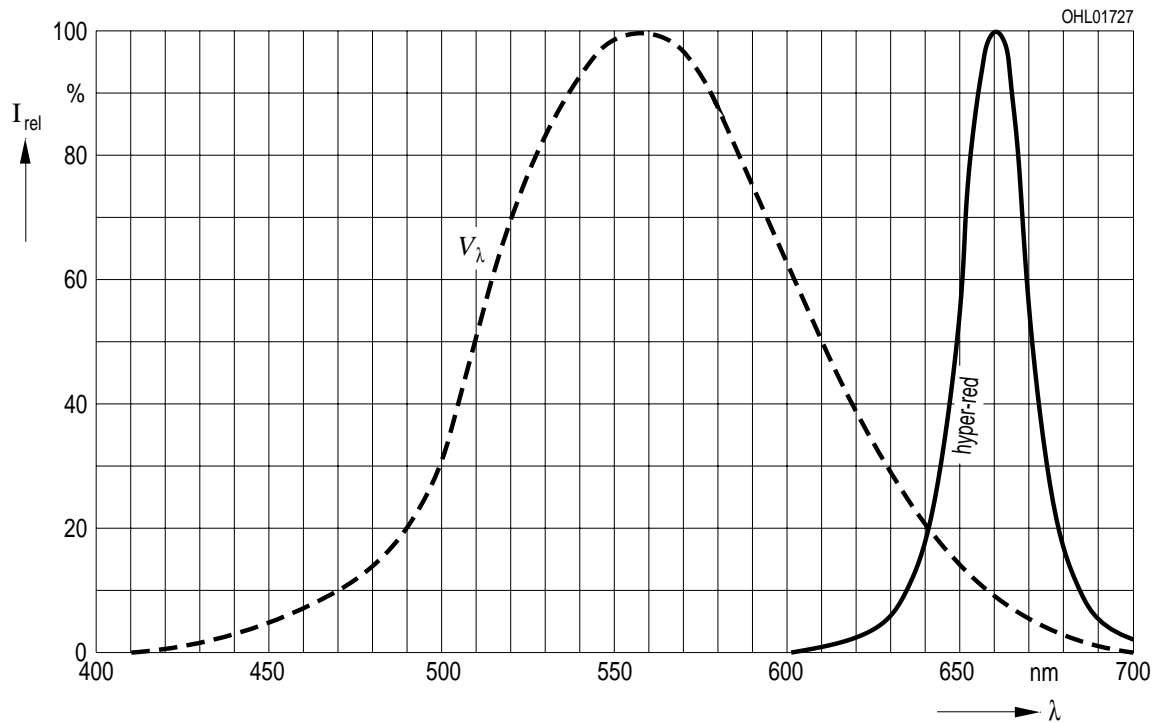
²⁾ Spannungswerte werden mit einer Stromeinprägungsdauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 20\text{ mA}$

Relative Spectral Emission

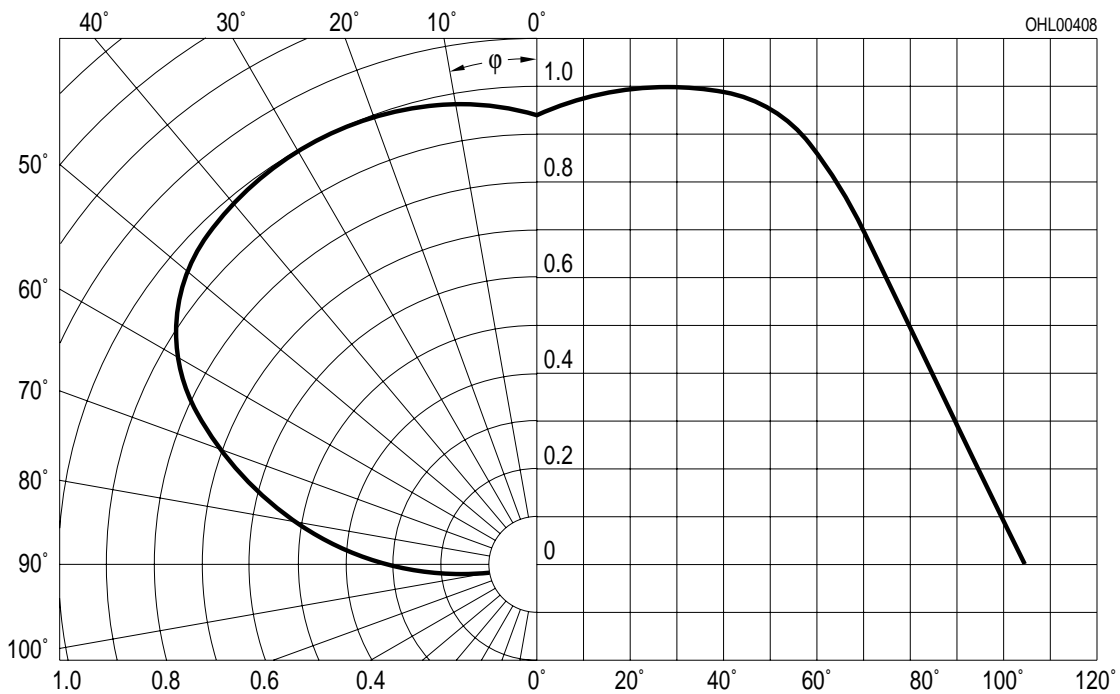
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



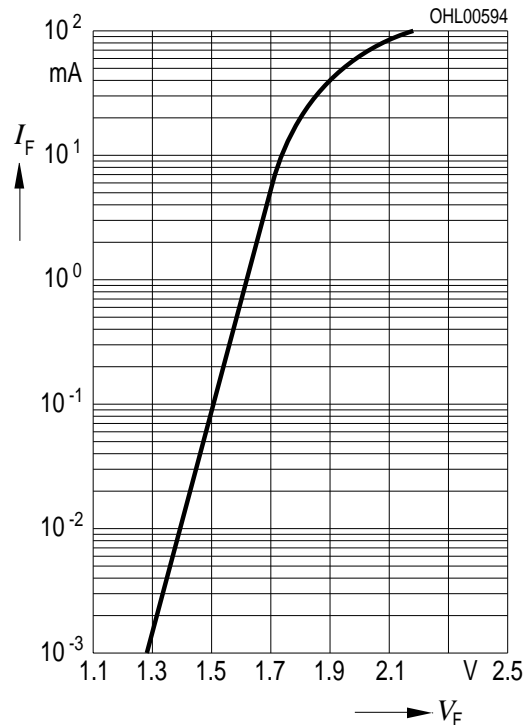
Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

Radiation Characteristic

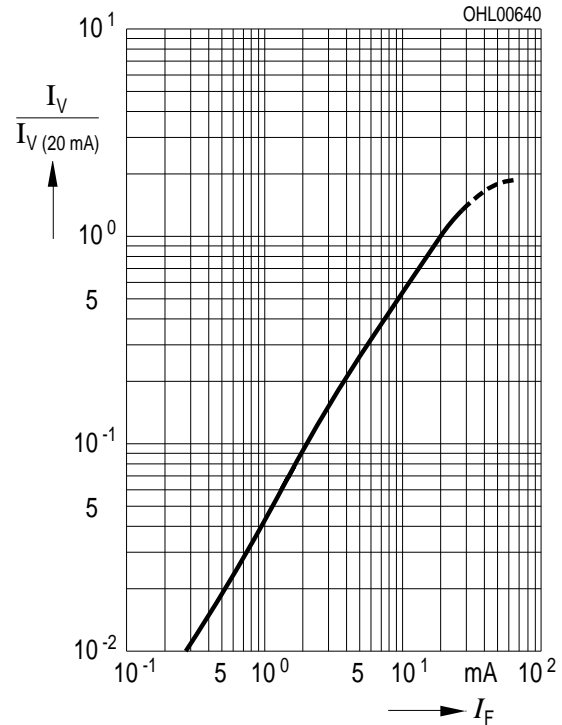


Durchlassstrom $I_F = f(V_F)$

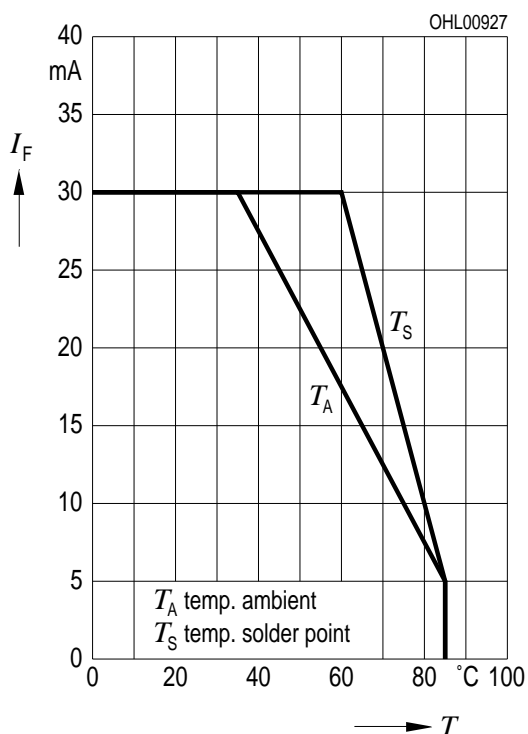
Forward Current

 $T_A = 25\text{ °C}$ Relative Lichtstärke $I_V/I_{V(20\text{ mA})} = f(I_F)$

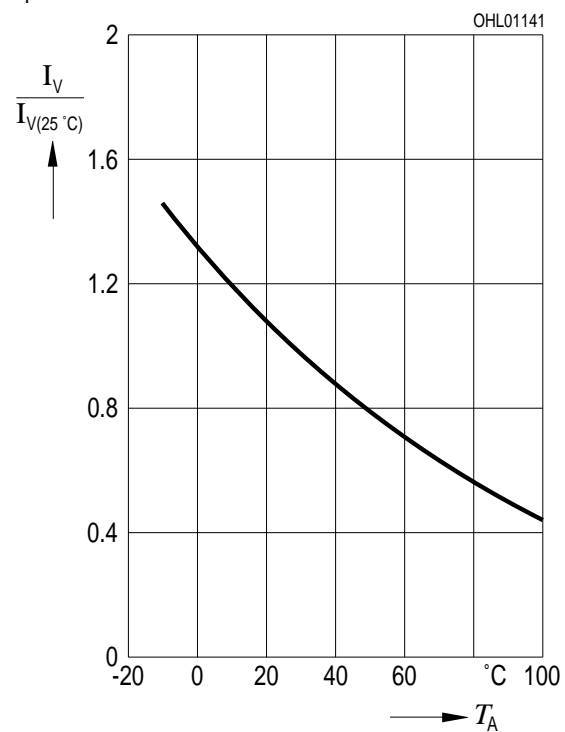
Relative Luminous Intensity

 $T_A = 25\text{ °C}$ Maximal zulässiger Durchlassstrom $I_F = f(T)$

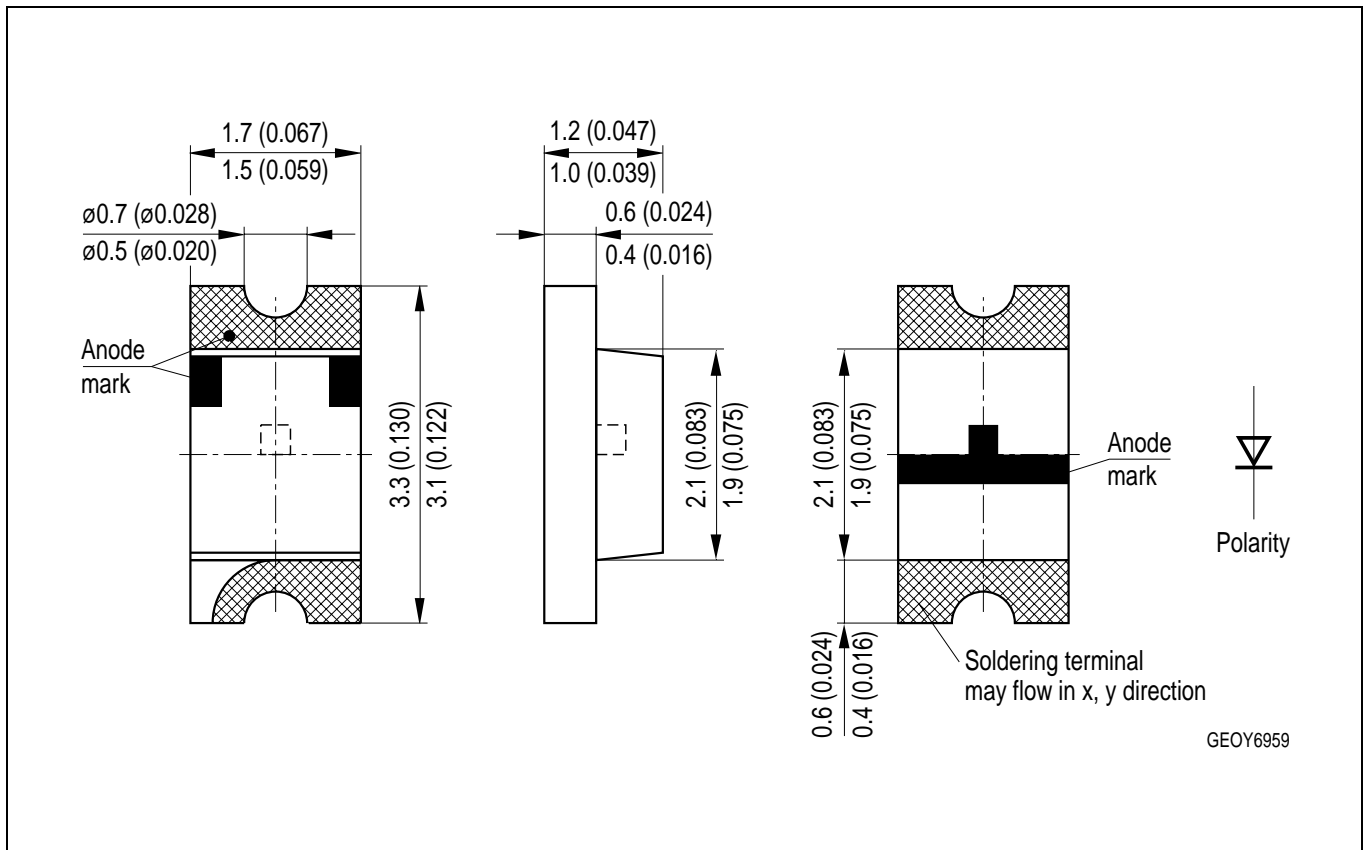
Max. Permissible Forward Current

Relative Lichtstärke $I_V/I_{V(25\text{ °C})} = f(T_A)$

Relative Luminous Intensity

 $I_F = 20\text{ mA}$ 

Maßzeichnung **Package Outlines**

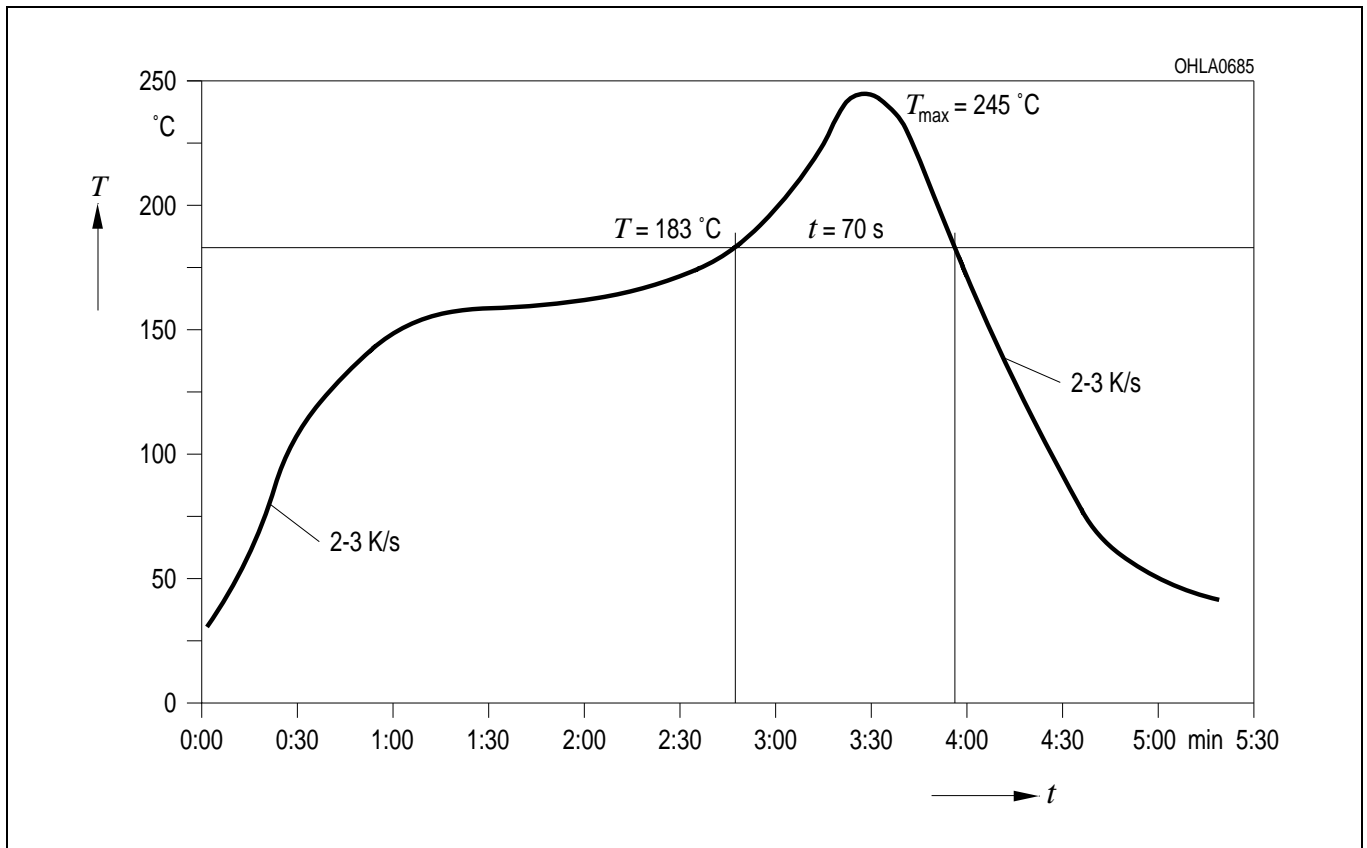


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

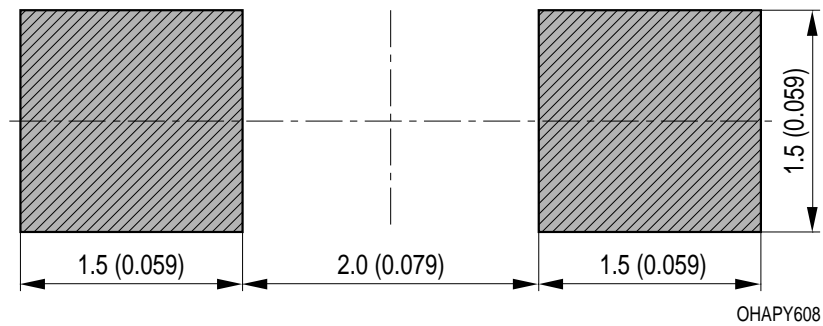
Gewicht / Approx. weight: 7.5 mg

Lötbedingungen Vorbehandlung nach JEDEC Level 2
Soldering Conditions Preconditioning acc. to JEDEC Level 2

IR-Reflow Lötprofil (nach IPC 9501)
IR Reflow Soldering Profile (acc. to IPC 9501)

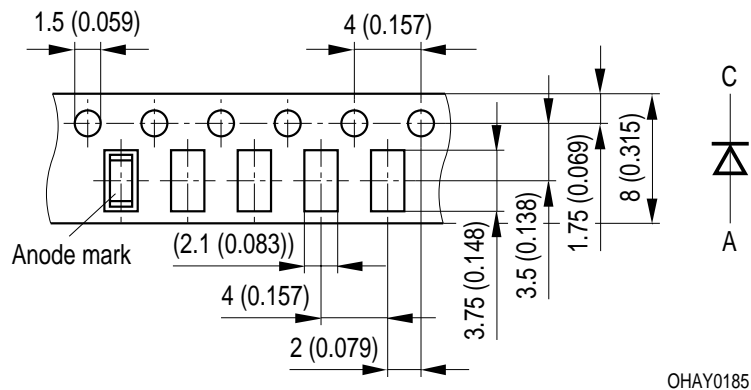


Empfohlenes Lötpaddesign IR Reflow Löten
Recommended Solder Pad IR Reflow Soldering



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Gurtung / Polarität und Lage Verpackungseinheit 3000/Rolle, ø180 mm
Method of Taping / Polarity and Orientation Packing unit 3000/reel, ø180 mm



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2002-04-11

Previous Version: 2002-03-14

Page	Subjects (major changes since last revision)
7	cathode marking
4	forward voltage
3	pad size from 16 mm ² to 5 mm ²

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Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

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